

PAE0521TEU

Low Capacitance Bidirectional Micro Packaged TVS Diodes for ESD Protection

General Description

The PAE0521TEU is designed with latest Punch-Through process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

Feature

- ●Peak Power Dissipation 50 W (8 x 20 us Waveform)
- ●Stand-off Voltage: 5.0 V
- ●Low capacitance (<6.0pF) for high-speed interfaces
- •No insertion loss to 1.0GHz
- •Replacement for MLV (0402)
- Protects I/O Port
- ●Low Clamping Voltage
- ●Low Leakage
- ●Low Capacitance
- Response Time is < 1 ns
- Meets MSL 1 Requirements
- ●ROHS compliant
- ●Solid-state Punch-Through TVS Process technology

Application

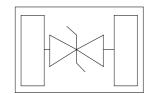
- ●High Speed Line :USB1.0/2.0, VGA, DVI, SDI,
- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV
- Cellular handsets and accessories
- •Portable instrumentation
- Peripherals

Protection solution to meet

●IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact) ●IEC61000-4-4 (EFT) 40A (5/50ns)









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Maximum Ratings (TA=25°C Unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (tp=8/20µs waveform)	Рррр	50	Watts	
ESD Rating per IEC61000-4-2: Contact		8	W W	
Air		15	KV	
Lead Soldering Temperature	TL	260 (10 sec.)	°C	
Operating Temperature Range	ΤJ	-55 ~ 150	°C	
Storage Temperature Range	Тѕтд	-55 ~ 150	°C	
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	C°	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not

normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

*Other voltages may be available upon request.

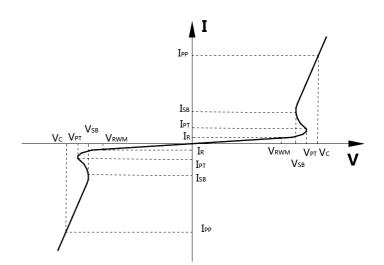
1. Non-repetitive current pulse, per Figure 1.

Electrical Characteristics (TA=25°C Unless otherwise specified)

	V	I _R	@ V _{RWM}	V _{SB} @ 50 mA	Vc	Capaci	tance
Device	V _{RWM}	(uA)		(Volts)	@ 1 A	@ $V_R = 0 V, 1 MHz (pF)$	
	(V)	Тур	Max	Min	(V)	Тур	Max
PAE0521TEU	5.0	0.05	1	5.3	9.0	3.0	6

Junction capacitance is measured in V_R =0V,F=1MHz

Symbol	Parameter	
VRWM	Working Peak Reverse Voltage	
Vpt	Punch-Through Voltage@ IPT	
Vsb	Snap-Back Voltage@ ISB	
V _C	Clamping Voltage @ IPP	
I _T	Test Current	
Irm	Leakage current at VRWM	
Ipp	Peak pulse current	
Co	Off-state Capacitance	
CJ	Junction Capacitance	

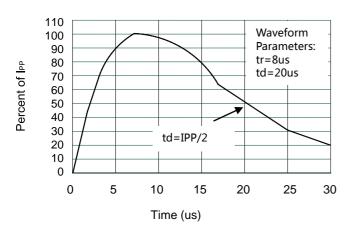




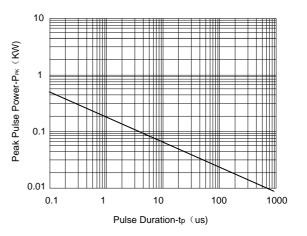
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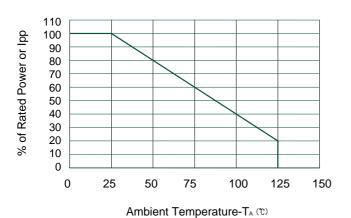
Typical Characteristics



Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve

1. -0.7540 dB 800MHz 2+ -1.2938 dB 1GHz 3# -3.2504 dB 2.5GHz 0 Insertion Loss (dB) 4. -19.431 dB 2.7GHz -6 -12 -18 -24 -30 -36 -42 10 MHz 3 GHz 1 GHz 1 MHz

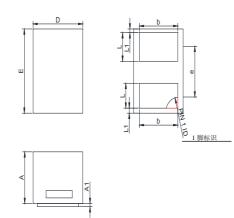
Insertion Loss S21



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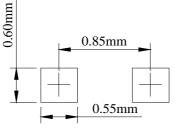
Package Information (DFN1006)

Case Material: Molded Plastic. UL Flammability

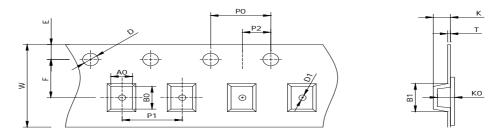


DIM	Millimeters		Inches		
DIM	Min	Max	Min	Max	
А	0.37	0.50	0.015	0.020	
A1	0.00	0.05	0.000	0.002	
D	0.55	0.65	0.022	0.026	
Е	0.95	1.05	0.037	0.041	
b	0.25	0.60	0.010	0.024	
e	0.65TYP		0.026TYP		
L	0.15	0.35	0.006	0.014	
L1	0.05REF		0.002REF		

Recommended Pad outline



DFN1006 Reel Dim



Package	Chip Size (mm)	Pocket Size B0×A0×K0(mm)	Tape Width	Reel Diameter	Quantity Per Reel	PO	P1
DFN1006	1.0×0.6×0.50	1.10×0.70×0.60	8mm	178mm(7")	5000/10000	4mm	4/2mm
D0	D1	Е	F	К	Т	W	
1.5mm	0.5mm	1.75mm	3.5mm	0.55mm	0.2mm	8mm	

Ordering Information

Part Number	Description	Quantity
PAE0521TEU	E0521TEU DFN1006 Reel	



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